

**TRIACS**

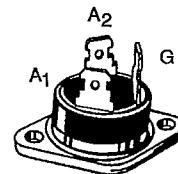
- GLASS PASSIVATED CHIP
- FAST-ON CONNEXIONS
- IGT SPECIFIED IN FOUR QUADRANTS
- INSULATING VOLTAGE 2500 VRMS
- UL RECOGNIZED (E81734)

**DESCRIPTION**

This new design of plastic insulated power triacs offers maximum efficiency with maximum ease of mounting.

**ADVANTAGES**

- NO TAPPING REQUIRED FOR FIXING
- EXCELLENT THERMAL IMPEDANCE AND HIGH RELIABILITY CONSTRUCTION

RD 91  
(Plastic)**ABSOLUTE RATINGS (limiting values)**

| Symbol             | Parameter  | Value                             |     | Unit                   |
|--------------------|--|-----------------------------------|-----|------------------------|
| $I_T(\text{RMS})$  | RMS on-state Current (360° conduction angle)   | $T_C = 75^\circ\text{C}$          | 40  | A                      |
| $I_{TSM}$          | Non Repetitive Surge Peak on-state Current ( $T_j$ initial = 25 °C - Half sine wave) | $t = 8.3 \text{ ms}$              | 315 | A                      |
|                    |  | $t = 10 \text{ ms}$               | 300 |                        |
| $I^2t$             | $I^2t$ Value for Fusing  | $t = 10 \text{ ms}$               | 450 | $\text{A}^2\text{s}$   |
| $di/dt$            | Critical Rate of Rise of on-state Current (1)  | Repetitive<br>$F = 50 \text{ Hz}$ | 10  | $\text{A}/\mu\text{s}$ |
|                    |  | Non<br>Repetitive                 | 50  |                        |
| $T_{stg}$<br>$T_j$ | Storage and Operating Junction Temperature Range                                     | -40 to 125<br>-40 to 125          |     | °C<br>°C               |

| Symbol    | Parameter                             | BTA 40- |      |      |      |      | Unit |
|-----------|---------------------------------------|---------|------|------|------|------|------|
|           |                                       | 200B    | 400B | 600B | 700B | 800B |      |
| $V_{DRM}$ | Repetitive Peak off-state Voltage (2) | 200     | 400  | 600  | 700  | 800  | V    |

(1)  $I_0 = 1 \text{ A}$   $di/dt = 1 \text{ A}/\mu\text{s}$ (2)  $T_j = 125^\circ\text{C}$ .**THERMAL RESISTANCES**

| Symbol                    | Parameter   | Value |  | Unit |
|---------------------------|---|-------|--|------|
| $R_{th (c-h)}$            | Contact (case-heatsink) with Grease                                 | 0.15  |  | °C/W |
| $R_{th (j-c)} \text{ DC}$ | Junction to Case for DC   | 1.2   |  | °C/W |
| $R_{th (j-c)} \text{ AC}$ | Junction to Case for 360 ° Conduction Angle ( $F = 50 \text{ Hz}$ ) | 0.9   |  | °C/W |

## GATE CHARACTERISTICS (maximum values)

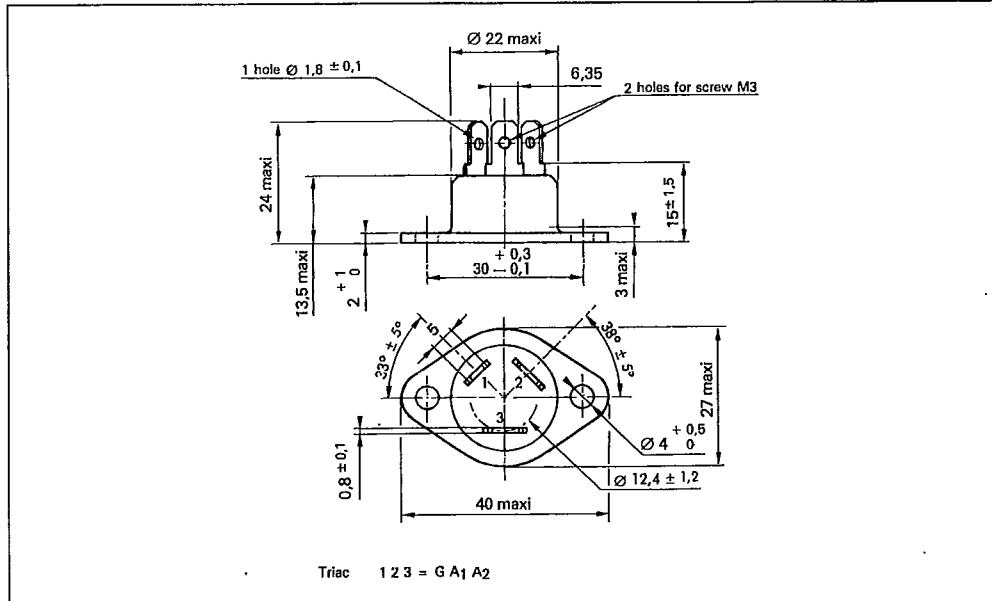
 $P_{GM} = 40 \text{ W}$  ( $t_p = 10 \mu\text{s}$ ) $P_G(\text{AV}) = 1 \text{ W}$  $I_{GM} = 10 \text{ A}$  ( $t_p = 10 \mu\text{s}$ ) $V_{GM} = 16 \text{ V}$  ( $t_p = 10 \mu\text{s}$ )

## ELECTRICAL CHARACTERISTICS

| Symbol        | Test Conditions   | Quadrants   | Min. | Typ. | Max. | Unit             |
|---------------|---|-------------|------|------|------|------------------|
| $I_{GT}$      | $T_j = 25^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \Omega$<br>Pulse Duration > 20 $\mu\text{s}$                      | I-II-III    | 1    |      | 50   | mA               |
|               |   | IV          | 1    |      | 100  |                  |
| $V_{GT}$      | $T_j = 25^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \Omega$<br>Pulse Duration > 20 $\mu\text{s}$                      | I-II-III-IV |      |      | 1.5  | V                |
| $V_{GD}$      | $T_j = 125^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$   | I-II-III-IV | 0.2  |      |      | V                |
| $I_H^*$       | $T_j = 25^\circ\text{C}$ $I_T = 500 \text{ mA}$ Gate Open   |             |      | 30   | 80   | mA               |
| $I_L$         | $T_j = 25^\circ\text{C}$ $V_D = 12 \text{ V}$ $I_G = 200 \text{ mA}$<br>Pulse Duration > 20 $\mu\text{s}$                 | I-II-III-IV |      |      | 100  | mA               |
| $V_{TM}^*$    | $T_j = 25^\circ\text{C}$ $I_{TM} = 60 \text{ A}$ $t_p = 10 \text{ ms}$  |             |      |      | 1.8  | V                |
| $I_{DRM}^*$   | $T_j = 125^\circ\text{C}$ $V_{DRM}$ Specified   |             |      | 1.5  | 6    | mA               |
| $dv/dt^*$     | $T_j = 125^\circ\text{C}$ Gate Open<br>Linear Slope up to $V_D = 67\% V_{DRM}$  |             | 250  |      |      | V/ $\mu\text{s}$ |
| $(dv/dt)_c^*$ | $T_C = 75^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$<br>$(di/dt)_c = 18 \text{ A/ms}$                            |             | 5    |      |      | V/ $\mu\text{s}$ |
| $t_{gt}$      | $T_j = 25^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$<br>$I_G = 1 \text{ A}$ $di_G/dt = 10 \text{ A}/\mu\text{s}$ | I-II-III-IV |      | 2.5  |      | $\mu\text{s}$    |

\* For either polarity of electrode A<sub>2</sub> voltage with reference to electrode A<sub>1</sub>.

## PACKAGE MECHANICAL DATA : RD 91 Plastic



Cooling method : by conduction (method C)

Marking : type number

Weight : 15 g

S G S-THOMSON

T-25-17

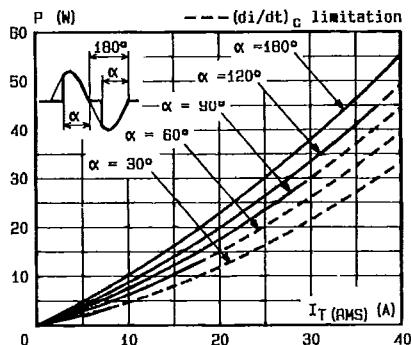


Fig.1 - Maximum mean power dissipation versus RMS on-state current ( $F = 60$  Hz).

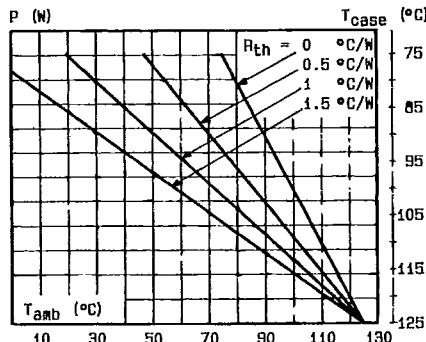


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

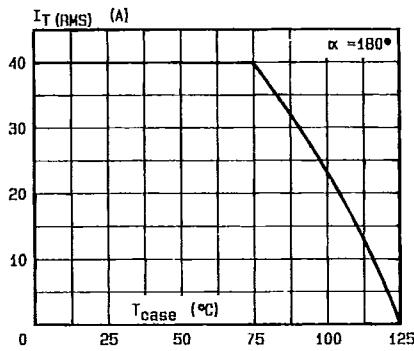


Fig.3 - RMS on-state current versus case temperature.

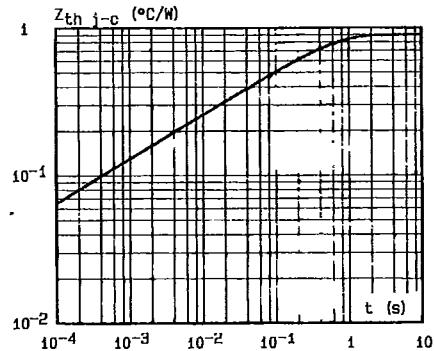


Fig.4 - Thermal transient impedance junction to case versus pulse duration.

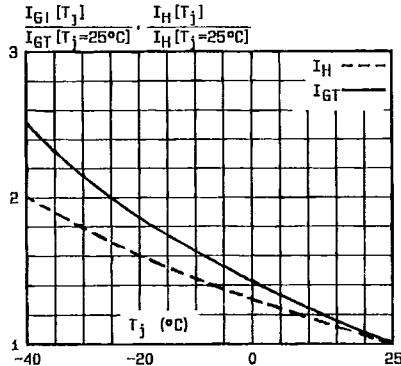


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

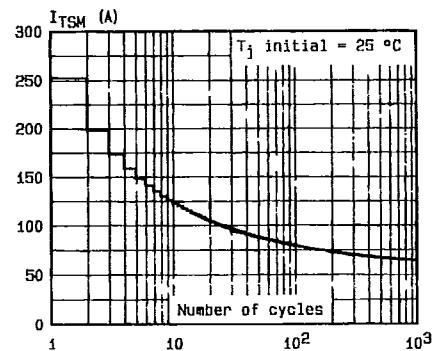


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

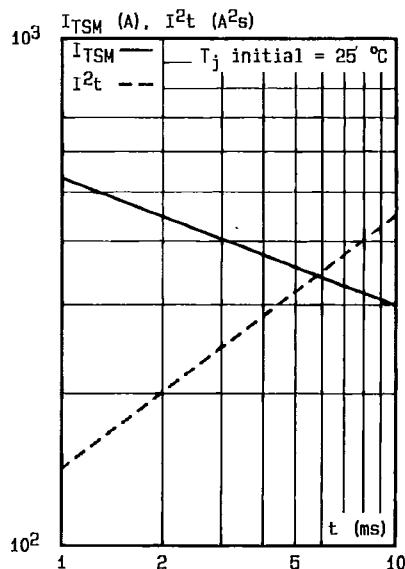


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

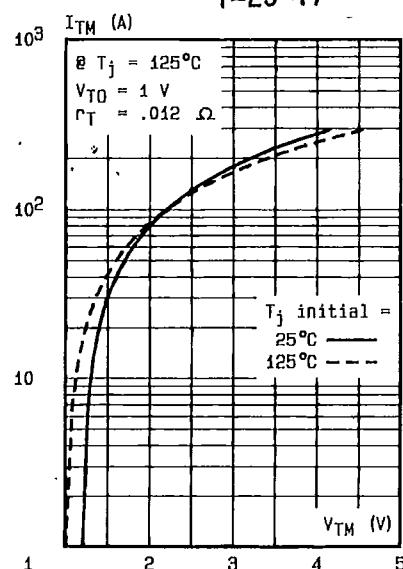


Fig.8 - On-state characteristics (maximum values).